# RENESAS HD74LV1GW07A

Dual Buffer Open Drain

REJ03D0076-0300 Rev.3.00 Sep 08, 2006

#### Da Description

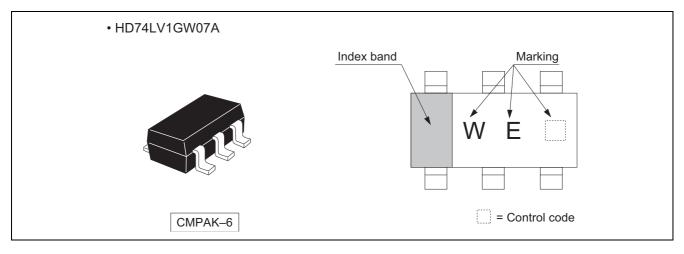
The HD74LV1GW07A has dual buffer open drain in a 6 pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

### Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Supply voltage range : 1.65 to 5.5 V Operating temperature range : -40 to +85°C
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@V<sub>CC</sub> = 0 V to 5.5 V) All outputs  $V_0$  (Max.) = 5.5 V (@V<sub>CC</sub> = 0 V, Output: Z)
- Output current 6 mA (@ $V_{CC}$  = 3.0 V to 3.6 V), 12 mA (@ $V_{CC}$  = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Ordering Information

| Part Name       | Package Type | Package Code<br>(Previous Code) | Package<br>Abbreviation | Taping Abbreviation<br>(Quantity) |
|-----------------|--------------|---------------------------------|-------------------------|-----------------------------------|
| HD74LV1GW07ACME | CMPAK-6 pin  | PTSP0006JA-A<br>(CMPAK-6V)      | СМ                      | E (3,000 pcs / Reel)              |

### **Outline and Article Indication**



### **Function Table**

| Input A | Output Y |
|---------|----------|
| Н       | Z        |
| L       | L        |

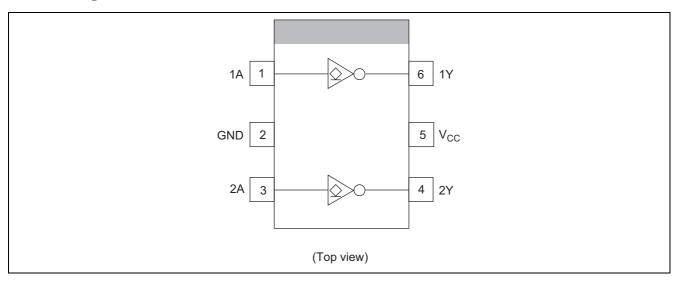
H : High level

L : Low level

Z : High impedance



### **Pin Arrangement**



### **Absolute Maximum Ratings**

| Item  | Symbol                              | Ratings                       | Unit | Test Conditions                     |
|---|-------------------------------------|-------------------------------|------|-------------------------------------|
| Supply voltage range  | V <sub>CC</sub>                     | -0.5 to 7.0                   | V    |                                     |
| Input voltage range *1  | VI                                  | -0.5 to 7.0                   | V    |                                     |
| Output voltage range *1, 2  | M                                   | -0.5 to V <sub>CC</sub> + 0.5 | V    | Output : L                          |
| Output voltage range  | Vo                                  | -0.5 to 7.0                   | v    | V <sub>CC</sub> : OFF or Output : Z |
| Input clamp current   | l <sub>IK</sub>                     | -20                           | mA   | V <sub>1</sub> < 0                  |
| Output clamp current  | I <sub>ОК</sub>                     | -50                           | mA   | V <sub>0</sub> < 0                  |
| Continuous output current   | lo                                  | ±25                           | mA   | $V_0 = 0$ to $V_{CC}$               |
| Continuous current through V <sub>CC</sub> or GND                             | I <sub>CC</sub> or I <sub>GND</sub> | ±50                           | mA   |                                     |
| Maximum power dissipation at Ta = $25^{\circ}$ C (in still air) <sup>*3</sup> | PT                                  | 200                           | mW   |                                     |
| Storage temperature   | Tstg                                | -65 to 150                    | °C   |                                     |

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. This value is limited to 5.5 V maximum.

3. The maximum package power dissipation was calculated using a junction temperature of 150°C.



### **Recommended Operating Conditions**

| Item                               | Symbol                | Min  | Max             | Unit    | Conditions                               |
|------------------------------------|-----------------------|------|-----------------|---------|--|
| Supply voltage range               | V <sub>CC</sub>       | 1.65 | 5.5             | V       |  |
| Input voltage range                | VI                    | 0    | 5.5             | V       |  |
| Output voltage range               | Vo                    | 0    | V <sub>cc</sub> | V       |  |
|                                    |                       | —    | 1               |         | V <sub>CC</sub> = 1.65 to 1.95 V         |
| Output current                     | I <sub>OL</sub>       | —    | 2               | mA      | $V_{CC}$ = 2.3 to 2.7 V                  |
|                                    |                       | —    | 6               | IIIA    | $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ |
|                                    |                       | —    | 12              |         | $V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$ |
|                                    |                       | 0    | 300             |         | V <sub>CC</sub> = 1.65 to 1.95 V         |
| Input transition rise or fall rate | $\Delta t / \Delta v$ | 0    | 200             | ns / V  | $V_{CC}$ = 2.3 to 2.7 V                  |
|                                    | $\Delta t / \Delta v$ | 0    | 100             | 115 / V | $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ |
|                                    |                       | 0    | 20              |         | $V_{CC}$ = 4.5 to 5.5 V                  |
| Operating free-air temperature     | Ta                    | -40  | 85              | °C      |  |

Note: Unused or floating inputs must be held high or low.

### **Electrical Characteristic**

|                             |                  |                                    |                      |      |                       |      | $Ta = -40 \text{ to } 85^{\circ}\text{C}$ |
|-----------------------------|------------------|------------------------------------|----------------------|------|-----------------------|------|---|
| ltem                        | Symbol           | V <sub>cc</sub> (V) * <sup>1</sup> | Min                  | Тур  | Max                   | Unit | Test Condition                            |
|                             |                  | 1.65 to 1.95                       | $V_{CC} \times 0.75$ | —    | —                     |      |   |
|                             | V                | 2.3 to 2.7                         | V <sub>CC</sub> ×0.7 | —    | —                     |      |   |
|                             | V <sub>IH</sub>  | 3.0 to 3.6                         | V <sub>CC</sub> ×0.7 | —    | —                     |      |   |
| Input voltage               |                  | 4.5 to 5.5                         | V <sub>CC</sub> ×0.7 | —    | —                     | V    |   |
| input voltage               |                  | 1.65 to 1.95                       | —                    | —    | V <sub>CC</sub> ×0.25 | v    |   |
|                             | V                | 2.3 to 2.7                         | —                    | _    | V <sub>CC</sub> ×0.3  |      |   |
|                             | VIL              | 3.0 to 3.6                         | —                    | _    | V <sub>CC</sub> ×0.3  |      |   |
|                             |                  | 4.5 to 5.5                         | —                    | _    | V <sub>CC</sub> ×0.3  |      |   |
|                             |                  | 1.8                                | —                    | 0.25 | —                     | V    |   |
| Hysteresis voltage          | V <sub>H</sub>   | 2.5                                | —                    | 0.30 | —                     |      | $V_{T}^{+} - V_{T}^{-}$                   |
| Hysteresis voltage          | ∨н               | 3.3                                | —                    | 0.35 | —                     |      | $v_{T} = v_{T}$                           |
|                             |                  | 5.0                                | —                    | 0.45 | —                     |      |   |
|                             |                  | Min to Max                         | —                    | _    | 0.1                   |      | I <sub>OL</sub> = 50 μA                   |
|                             |                  | 1.65                               | —                    | _    | 0.3                   | V    | I <sub>OL</sub> = 1 mA                    |
| Output voltage              | V <sub>OL</sub>  | 2.3                                | —                    | _    | 0.4                   |      | $I_{OL} = 2 \text{ mA}$                   |
|                             |                  | 3.0                                | —                    | _    | 0.44                  |      | $I_{OL} = 6 \text{ mA}$                   |
|                             |                  | 4.5                                | —                    | _    | 0.55                  |      | I <sub>OL</sub> = 12 mA                   |
| Input current               | I <sub>IN</sub>  | 0 to 5.5                           | —                    | _    | ±1                    | μA   | $V_{IN} = 5.5 \text{ V or GND}$           |
| Off state                   | I <sub>oz</sub>  | Min to Max                         | _                    | _    | ±5                    | μA   | $V_{0} = 5.5 \text{ V or GND}$            |
| output current              | 102              |                                    |                      |      | _0                    | μι   | -   |
| Quiescent<br>supply current | I <sub>CC</sub>  | 5.5                                | _                    | _    | 10                    | μA   | $V_{IN} = V_{CC}$ or GND,<br>$I_O = 0$    |
| Output leakage<br>current   | I <sub>OFF</sub> | 0                                  | _                    | _    | 5                     | μΑ   | $V_{\rm IN}$ or $V_{\rm O}$ = 0 to 5.5 V  |
| Input capacitance           | CIN              | 3.3                                | —                    | 3.0  |                       | pF   | $V_{IN} = V_{CC}$ or GND                  |

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Ta = -40 to  $85^{\circ}C$ 



## **Switching Characteristics**

 $V_{CC} = 1.8 \pm 0.15 \text{ V}$ 

| Item        | Symbol          | -   | Га = 25°С | ;    | Ta = -40 to 85°C |      | Unit | Test                   | FROM    | то       |
|-------------|-----------------|-----|-----------|------|------------------|------|------|------------------------|---------|----------|
| nem         | Symbol          | Min | Тур       | Max  | Min              | Max  | Unit | Conditions             | (Input) | (Output) |
| Propagation | t <sub>ZL</sub> | _   | 12.6      | 22.0 | 1.0              | 24.0 | 20   | C <sub>L</sub> = 15 pF | ٨       | V        |
| delay time  | t <sub>LZ</sub> |     | 19.7      | 33.0 | 1.0              | 36.0 | ns   | C <sub>L</sub> = 50 pF | A       | T        |

 $V_{CC}=2.5\pm0.2~V$ 

| Item        | Symbol          |     | Га = 25°С | ;    | Ta = -40 | to 85°C | Unit | Test                   | FROM    | то       |
|-------------|-----------------|-----|-----------|------|----------|---------|------|------------------------|---------|----------|
| nem         | Symbol          | Min | Тур       | Max  | Min      | Max     | Unit | Conditions             | (Input) | (Output) |
| Propagation | t <sub>ZL</sub> | _   | 7.0       | 11.7 | 1.0      | 14.0    | 20   | C <sub>L</sub> = 15 pF | ۸       | V        |
| delay time  | t <sub>LZ</sub> |     | 10.5      | 15.5 | 1.0      | 18.0    | ns   | C <sub>L</sub> = 50 pF | A       | I        |

 $V_{CC}=3.3\pm0.3~V$ 

| Item        | Symbol          | ٦   | Га = 25°С | ;    | Ta = -40 | to 85°C | Unit | Test                   | FROM    | то       |
|-------------|-----------------|-----|-----------|------|----------|---------|------|------------------------|---------|----------|
| nem         | Symbol          | Min | Тур       | Max  | Min      | Max     | Unit | Conditions             | (Input) | (Output) |
| Propagation | t <sub>ZL</sub> | Ι   | 5.0       | 7.1  | 1.0      | 8.5     | 20   | C <sub>L</sub> = 15 pF | ٨       | V        |
| delay time  | t <sub>LZ</sub> | _   | 7.5       | 10.6 | 1.0      | 12.0    | ns   | C <sub>L</sub> = 50 pF | A       | I        |

 $V_{CC}=5.0\pm0.5~V$ 

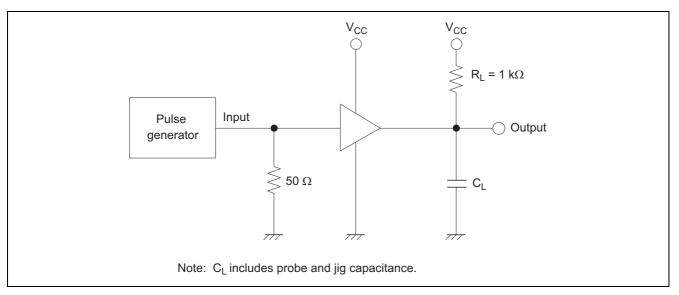
| Item        | Symbol          | -   | Га = 25°С | ;   | Ta = -40 | to 85°C | Unit | Test                   | FROM    | то       |
|-------------|-----------------|-----|-----------|-----|----------|---------|------|------------------------|---------|----------|
| item        | Symbol          | Min | Тур       | Max | Min      | Max     | Onic | Conditions             | (Input) | (Output) |
| Propagation | t <sub>ZL</sub> |     | 3.8       | 5.5 | 1.0      | 6.5     | ns   | C <sub>L</sub> = 15 pF | ٨       | v        |
| delay time  | t <sub>LZ</sub> | _   | 5.3       | 7.5 | 1.0      | 8.5     | 115  | $C_L = 50 \text{ pF}$  | A       | I        |

## **Operating Characteristics**

 $C_L = 50 \text{ pF}$ 

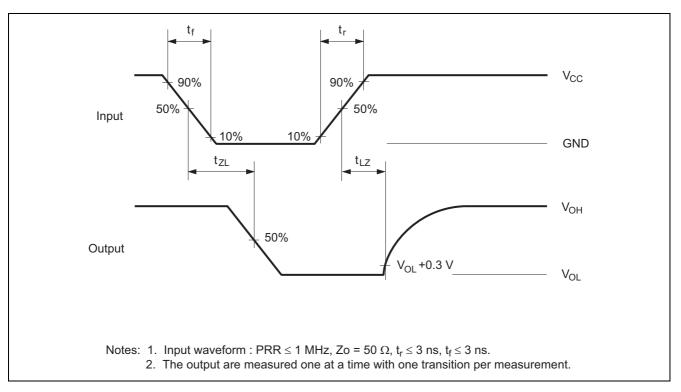
| ltem              | Symbol   | V., 00              | ٦   | Га = 25°С | ;   | Unit | Test Conditions |  |
|-------------------|----------|---------------------|-----|-----------|-----|------|-----------------|--|
| nem               | Symbol   | V <sub>cc</sub> (V) | Min | Тур       | Max | Unit | Test Conditions |  |
| Power dissipation | <b>C</b> | 3.3                 | _   | 8.5       |     | ρF   | f = 10 MHz      |  |
| capacitance       | CPD      | 5.0                 | —   | 10.0      |     | рг   |                 |  |

## **Test Circuit**

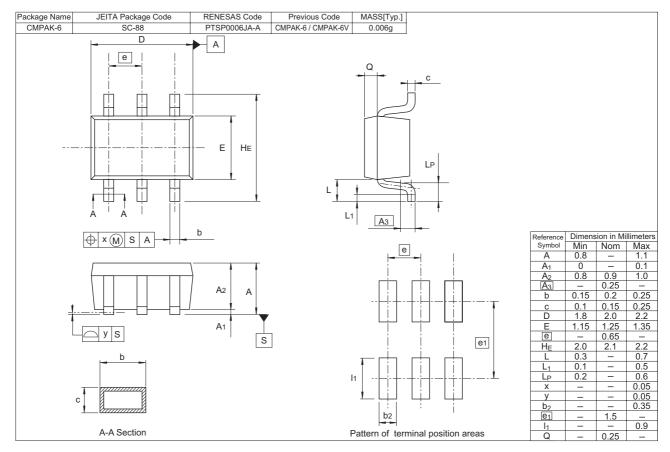




#### Waveform



### **Package Dimensions**





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